## **CLAIMS**

## What is claimed is:

1 1 An assembly for a die compris	ing:
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- a lid; and
- a solderable thermally conductive element to couple a die to the lid. 3
- The assembly recited in claim 1 wherein the lid comprises material from the 1 2.
- group consisting of copper and aluminum-silicon-carbide. 2
- The assembly recited in claim 1 wherein the solderable thermally conductive 3. 1
- element comprises material, including one or more alloys, from the group consisting 2
- of tin, bismuth, silver, indium, and lead. 3
- The assembly recited in claim 1 wherein the lid comprises at least one metal 1 4.
- or organic layer to which the thermally conductive element can be coupled. 2
- The assembly recited in claim 4 wherein the at least one metal or organic 1 5.
- layer comprises nickel or gold. 2
  - The assembly recited in claim 1 and further comprising: 6.
- 1 a die comprising at least one metal layer to which the solderable thermally 2
- conductive element can be coupled. 3
- The assembly recited in claim 6 wherein the at least one metal layer 1 7.
- comprises material, including one or more alloys, from the group consisting of 2
- titanium, chromium, zirconium, nickel, vanadium, and gold. 3
- An integrated circuit package comprising: 1
- a substrate; 2
- a die positioned on a surface of the substrate; 3
- a lid positioned over the die; and 4
- a solderable thermally conductive element coupling the die and the lid. 5

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- 1 9. The integrated circuit package recited in claim 8 wherein the lid comprises a
- 2 support member coupled to the substrate.
- 1 10. The integrated circuit package recited in claim 8 wherein the lid comprises
- 2 material from the group consisting of copper and aluminum-silicon-carbide.
- 1 11. The integrated circuit package recited in claim 8 wherein the lid comprises at
- 2 least one metal or organic layer to which the thermally conductive element is
- 3 coupled.
- 1 12. The integrated circuit package recited in claim 11 wherein the at least one
- 2 metal or organic layer comprises nickel or gold.
- 1 13. The integrated circuit package recited in claim 8 wherein the solderable
- 2 thermally conductive element comprises material, including one or more alloys,
- 3 from the group consisting of tin, bismuth, silver, indium, and lead.
- 1 14. The integrated circuit package recited in claim 8 wherein the substrate is an
- 2 organic substrate and wherein the die is coupled to the substrate through a land grid
- 3 array.
- 1 15. The integrated circuit package recited in claim 8 wherein the die comprises
- at least one metal layer to which the thermally conductive element is coupled.
- 1 16. The integrated circuit package recited in claim 15 wherein the at least one
- 2 metal layer comprises material, including one or more alloys, from the group
- 3 consisting of titanium, chromium, zirconium, nickel, vanadium, and gold.
- 1 17. An electronic assembly comprising:
- 2 at least one integrated circuit package comprising:
- 3 a substrate;
- a die positioned on a surface of the substrate;
- 5 a lid positioned over the die; and

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- a solderable thermally conductive element coupling the die and the lid.
- 1 18. The electronic assembly recited in claim 17 wherein the lid comprises a
- 2 support member coupled to the substrate.
- 1 19. The electronic assembly recited in claim 17 wherein the solderable thermally
- 2 conductive element comprises material, including one or more alloys, from the
- group consisting of tin, bismuth, silver, indium, and lead.
- 1 20. The electronic assembly recited in claim 17 wherein the substrate is an
- 2 organic substrate and wherein the die is coupled to the substrate through a land grid
- 3 array.
- 1 21. An electronic system comprising an electronic assembly having at least one
- 2 integrated circuit package comprising:
- a substrate;
- a die positioned on a surface of the substrate;
- 5 a lid positioned over the die; and
- a solderable thermally conductive element coupling the die and the lid.
- The electronic system recited in claim 21 wherein the solderable thermally
- The electronic system recited in standard conductive element comprises material, including one or more alloys, from the
- 3 group consisting of tin, bismuth, silver, indium, and lead.
- 1 23. The electronic system recited in claim 21 wherein the substrate is an organic
- 1 23. The electronic system recited in standard substrate, wherein the die is coupled to the substrate through a land grid array, and 2
- 3 wherein the lid comprises a support member coupled to the substrate.
- 1 24. A data processing system comprising:
- 2 a bus coupling components in the data processing system;
- a display coupled to the bus;
- 4 external memory coupled to the bus; and

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5	a processor coupled to the bus and comprising an electronic assembly	
6	including at least one integrated circuit package comprising:	
7	a substrate;	
8	a die positioned on a surface of the substrate;	
9	a lid positioned over the die; and	
10	a solderable thermally conductive element coupling the die and t	the
	11.1	
11	lid.	

- 1 25. The data processing system recited in claim 24 wherein the solderable
- thermally conductive element comprises material, including one or more alloys,
- 3 from the group consisting of tin, bismuth, silver, indium, and lead.
- 1 26. The data processing system recited in claim 24 wherein the substrate is an
- 2 organic substrate and wherein the die is coupled to the substrate through a land grid
- 3 array.
- 1 27. A method of fabricating an integrated circuit package, the method
- 2 comprising:
- forming at least one metal layer on a surface of a die;
- 4 mounting the die on a substrate;
- 5 positioning a surface of a lid adjacent the layer of solder material; and
- 6 applying solder material between the at least one metal layer and the surface
- 7 of the lid;
- 8 melting the solder material to physically couple the lid to the die.
- 1 28. The method recited in claim 27 wherein the solder material has a relatively
- 2 high thermal conductivity and a relatively low melting point.
- 1 29. The method recited in claim 27 wherein the substrate comprises organic
- 2 material having a relatively high thermal coefficient of expansion relative to that of
- 3 the die.

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1 30. The method recited in claim 27 and further comprising forming at least one metal or organic layer on the surface of the lid prior to applying solder material.

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